Supporting Information for

Ligand-directed rapid formation of ultralong ZnO nanowires by oriented attachment for UV photodetectors

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Figure S1. Low-magnification SEM images and corresponding length and diameter distribution of the nanowires (a, b) and microrods (c, d). The size distribution was estimated by directly measuring about 200 particles from the SEM images.



Figure S2. TEM image (a) and SAED patterns performed at different locations along a single nanowire (b-e); (f) a typical HRTEM image recorded on a large area of a single nanowire.



Figure S3. SEM images (a-c) of the nanowire networks with varying density on the electrodes at different concentration (g·L⁻¹) of the spin-coating suspensions: (a) 3; (b) 0.5; (c) 15; scale bars: 50 μ m; (d) photocurrent rise/decay curves of the UV photodetectors based on the the nanowire networks with different densities at a bias of 5.0 V.